TOSHIBA Field-Effect Transistor Silicon N-Channel MOS Type

SSM6K202FE

- High-Speed Switching Applications
- Power Management Switch Applications
- 1.8 V drive
- Low ON-resistance: $R_{on} = 145 \text{ m}\Omega \text{ (max)} (@V_{GS} = 1.8V)$

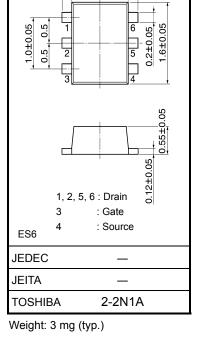
 R_{on} = 101 mΩ (max) (@V_{GS} = 2.5V) R_{on} = 85 mΩ (max) (@V_{GS} = 4.0V)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Drain-source voltage		V _{DS}	30	V	
Gate-source voltage		V _{GSS}	± 12	V	
Drain current	DC	I _D	2.3	A	
	Pulse	I _{DP}	4.6		
Drain power dissipation		P _D (Note 1)	500	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature		T _{stg}	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



1.6±0.05

1.2±0.05

Note 1: Mounted on an FR4 board

(25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 645 mm²)

Electrical Characteristics (Ta = 25°C)

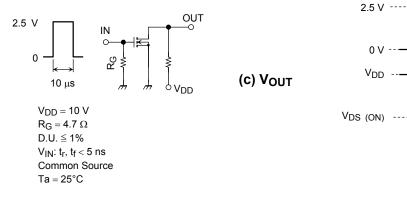
Charae	cteristic	Symbol	Test Condition	Min	Тур.	Мах	Unit
Drain–source breakdown voltage		V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0$	30		_	V
		V (BR) DSX	$I_D = 1 \text{ mA}, V_{GS} = -12 \text{ V}$	18	_		V
Drain cutoff curre	nt	IDSS	$V_{DS} = 30 V, V_{GS} = 0$			1	μA
Gate leakage cur	rent	I _{GSS}	$V_{GS}=\pm12~V,~V_{DS}=0$			±1	μA
Gate threshold vo	ltage	V _{th}	$V_{DS} = 3 V, I_D = 1 mA$	0.4		1.0	V
Forward transfer	admittance	Y _{fs}	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 1.5 \text{ A}$ (Note2	3.9	7.8		S
Drain-source ON-resistance		R _{DS (ON)}	$I_D = 1.5 \text{ A}, V_{GS} = 4.0 \text{ V}$ (Note2		66	85	mΩ
			$I_D = 1.0 \text{ A}, V_{GS} = 2.5 \text{ V}$ (Note2	—	78	101	
			$I_D = 0.5 \text{ A}, V_{GS} = 1.8 \text{ V}$ (Note2		95	145	
Input capacitance		C _{iss}	$V_{DS}=10~V,~V_{GS}=0,~f=1~MHz$	—	270	_	pF
Output capacitance		Coss	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$		56	_	pF
Reverse transfer	capacitance	C _{rss}	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$		47		pF
Switching time	Turn-on time	t _{on}	$\label{eq:VDD} \begin{split} &V_{DD} = 10 \; V, I_{D} = 2 \; A, \\ &V_{GS} = 0 \; to \; 2.5 \; V, R_{G} = 4.7 \; \Omega \end{split}$		20	_	ns
	Turn-off time	toff		_	31	_	
Drain-source forv	vard voltage	V _{DSF}	$I_D = -2.3 \text{ A}, V_{GS} = 0 \text{ V}$ (Note2) —	- 0.85	- 1.2	V

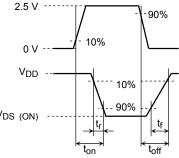
Unit: mm

Switching Time Test Circuit

(a) Test Circuit

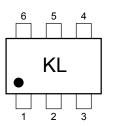
(b) V_{IN}

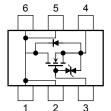




Marking

Equivalent Circuit (top view)





Notice on Usage

 V_{th} can be expressed as the voltage between gate and source when the low operating current value is $I_D = 1$ mA for this product. For normal switching operation, $V_{GS (on)}$ requires a higher voltage than V_{th} and $V_{GS (off)}$ requires a lower voltage than V_{th} .

(The relationship can be established as follows: $V_{GS (off)} < V_{th} < V_{GS (on)}$.)

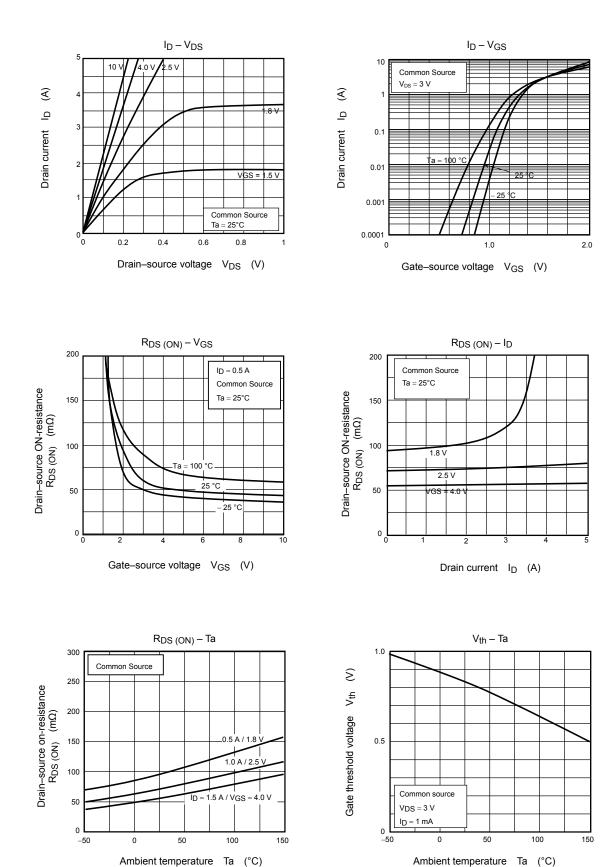
Take this into consideration when using the device.

Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

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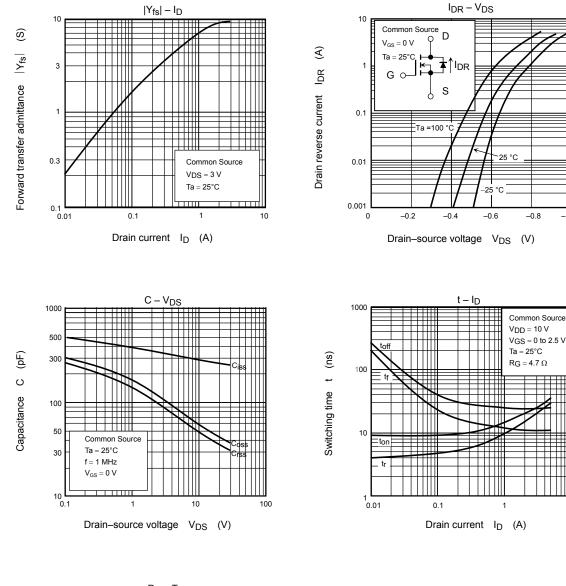
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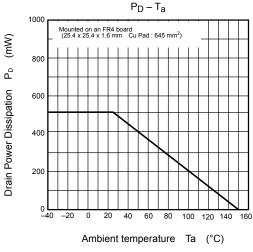


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20070701-EN GENERAL

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